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# Crystallite structure, microstructure, dielectric and ferroelectric properties of $BaTi_{0.99}Fe_{0.01}O_{3-\delta}$ ceramic

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The BaTiO<sub>3</sub> and BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3- $\delta}$ </sub> ceramics were prepared via a solid state reaction method. The crystallite structure, microstructure, dielectric and ferroelectric properties of the ceramics were studied. The Fe<sup>3+</sup> ions were soluble into BaTiO<sub>3</sub> lattice with the given concentration. The crystallite structure was investigated by using Rietveld refinement and the results show a decrease in the tetragonality due to the doping of Fe<sup>3+</sup>. Both ceramics have dense microstructures. The mean grain size of BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3- $\delta}$ </sub> is larger than that of BaTiO<sub>3</sub>. Compared with BaTiO<sub>3</sub>, BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3- $\delta}</sub> demonstrates decreased dielectric constant, Curie temperature and ferroelectric properties. A diffuse phase transition behavior was observed on the dielectric constant-temperature curves of BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-<math>\delta}$ </sub>. The differences in dielectric and ferroelectric properties between the two ceramics were discussed.</sub>

Key words: Ceramic, Crystallite structure, Microstructure, Dielectric properties, Ferroelectric properties.

### Introduction

Barium titanate (BaTiO<sub>3</sub>) is one of classical ferroelectric materials, which has been widely used in electronics industry, such as energy converting systems, multilayer capacitors, sensors with positive temperature coefficient of resistivity, and so on [1-4]. Due to the intrinsic capability of the perovskite structure to host ions with different size, a large number of different dopants can be accommodated in the BaTiO<sub>3</sub> lattice. Doping is performed either at the Ba<sup>2+</sup> and/or Ti<sup>4+</sup> sites of BaTiO<sub>3</sub>. Different dopants into BaTiO<sub>3</sub> lead to changes in structure and electrical properties [5-6]. BaTiO<sub>3</sub>-based ceramics with donor dopants (such as  $Nb^{3+}$ , La<sup>3+</sup>) at a relatively low concentration show roomtemperature semiconducting character, while the addition of acceptor dopants leads to insulators at room temperature [7-8]. Acceptor dopants of the transition metal ions (such as Ni<sup>2+</sup>, Fe<sup>3+</sup>, Co<sup>3+</sup>, etc) were incorporated into BaTiO<sub>3</sub> for the preparation of multilayer ceramic capacitors to allow for the use of cheaper metal electrodes.

Oxygen vacancy is a very significant factor that can affect crystallite structure, microstructure and electrical properties of oxide ceramics. Zhang et al. reported that sintering  $(Ba_{0.95}Ca_{0.05})(Ti_{0.88}Zr_{0.12})O_3$  ceramics in a protective atmosphere could increase dielectric constant, which is related to the change in oxygen vacancy concentration [9].  $(K_{0.5}Na_{0.5})NbO_3$  ceramics demonstrate obvious diffuse character of orthorhombic-

tetragonal and tetragonal-cubic phase transitions as they have high oxygen vacancy concentration [10]. Jung et al. found that the structural change of grain boundary and related grain growth behavior of BaTiO<sub>3</sub> were close related to oxygen partial pressure during sintering [11]. Fujii et al. reported that the moving of domain walls in BaTiO<sub>3</sub> was influenced by oxygen vacancy defects [12]. These results show that oxygen vacancy is very important in determining structure and electrical properties of ferroelectric ceramics.

In this work, the BaTiO<sub>3</sub> and Fe<sup>3+</sup>-doped BaTiO<sub>3</sub> ceramics were prepared via the solid state reaction method. The crystallite structure, microstructure, dielectric and ferroelectric properties of both ceramics were studied comparatively. The doping of Fe<sup>3+</sup> into BaTiO<sub>3</sub> can induce oxygen vacancies in the ceramic. The changes in structure and electrical properties of the ceramics were discussed according to the effect of oxygen vacancies.

### **Experimental Methods**

The BaTiO<sub>3</sub> and BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3- $\delta$ </sub> ceramics were prepared via the conventional solid state reaction method. Starting materials are BaCO<sub>3</sub> ( $\geq$  99%), TiO<sub>2</sub> ( $\geq$  99%) and Fe<sub>2</sub>O<sub>3</sub> ( $\geq$  99%) powders. All raw powders were baked at 100 °C for 24 hrs to remove water and immediately weighed according to the chemical formula. The powders were mixed with zirconia media and ethanol by ball milling for 24 hrs. After drying, the milled powders were calcined at 1000 °C for 2 hrs. The calcined powders were milled again for 12 hrs and then pulverized with approximately 5 wt% polyvinyl alcohol. Pellets of 11.5 mm in diameter and approximately 1.5 mm in thickness were pressed under a uniaxial

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pressure of 300 MPa and burned out the binder at 500 °C for 2 hrs. The pellets were sintered at 1300 °C for 5 hrs. Heating and cooling rates were 3 °C/min.

Crystallite structure was investigated by means of Xray diffraction (XRD, Rigaku D/Max 2550) using a Cu  $K_a$  radiation. The XRD measurement was made at 40 kV and 100 mA. To obtain the lattice parameters of the ceramics, the XRD patterns were refined via the program of Materials Analysis Using Diffraction (MAUD) [13]. Bulk densities ( $\rho_b$ ) of the ceramics were measured via the Archimedes method. The theoretical densities ( $\rho_{th}$ ) were calculated using the following equation:

$$\rho_{\rm th} = \mathbf{M} \times \mathbf{Z} / (6.02 \times 10^{23} \times \mathbf{V}) \tag{1}$$

where *M* is the molar mass of the ceramics, Z is the number of subcell and V is the lattice volume. The relative densities ( $\rho_r$ ) were obtained via the following formula:

$$\rho_{\rm r} = \rho_{\rm b} / \rho_{\rm th} \tag{2}$$

Microstructure of the ceramics was observed using scanning electron microscope (Quanta 200 SEM, FEI Co., Eindhoven, Netherlands). Mean size of grains was determined by means of the linear intercept method.

In order to characterize dielectric and ferroelectric properties of the ceramics, external surfaces of the ceramics were mechanically ground and polished using fine–grained emery paper under cold water circulation. Then, silver electrodes were coated and fired at 650 °C for 30 min. Ferroelectric hysteresis loops were measured at 50 Hz and room temperature in silicon oil with a radiant precision workstation ferroelectric testing system (Radiant Technologies Inc.). Dielectric measurement was performed using an Agilent E4980A precision LCR meter from room temperature to 200 °C at 3 °C/min.

## **Results and Discussions**

XRD curves of  $BaTiO_3$  and  $BaTi_{0.99}Fe_{0.01}O_{3\text{-}\delta}$  are shown in Fig. 1(a, b). Both specimens demonstrate typical ABO<sub>3</sub> perovskite diffraction peaks. No trace of secondary phases was detected within the resolution limit of the apparatus. A magnified view of peaks corresponding to the maximum intensity is shown in Fig. 1(c). It is noted that the XRD peak position of BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-8</sub> shifts towards lower diffraction angle direction compared with that of BaTiO<sub>3</sub>. This can be visualized as an evidence for the dissolution of Fe<sup>3+</sup> into the lattice structure. According to Shannon's effective ionic radii, Fe<sup>3+</sup> with a coordination number of six has radius of 0.0645 nm, while Ti<sup>4+</sup> with a coordination number of six possesses radius of 0.0605 nm [14]. It is known that the substitution site is mainly determined by ionic radius and charge. Though the charge of Fe<sup>3+</sup> is different from that of Ti<sup>4+</sup>, the



**Fig. 1.** Rietveld analysis results of XRD pattern for (a) BaTiO<sub>3</sub> and (b) BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3- $\delta$ </sub>. Circles indicate the experiment data and the refinement data are the continuous line overlapping them. The lowest curves in (a) and (b) show the difference between experimental data and refinement data. XRD patterns at 2 theta between 30-33 ° (c) and 44-47 ° (d).

radius of Fe<sup>3+</sup> is compatible with that of Ti<sup>4+</sup>. So, Fe<sup>3+</sup> should substitute Ti<sup>4+</sup>. With a relatively large size, the incorporation of Fe<sup>3+</sup> increased the mean radius of the B-site. This led to an increase in the dimension of the unit cells. On the other hand, oxygen vacancies can be formed in BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-8</sub> to maintain the overall electrical neutrality according to the Kröger-Vink equation:

$$Fe^{3+} \xrightarrow{BaTiO_3} 2Fe'_{Ti} + V_O^{\bullet}$$
 (3)

From the viewpoint of crystal chemistry, the creation of oxygen vacancies can contribute to a decrease in the unit cell dimensions, which should cause a shift of XRD peaks towards higher diffraction angle direction.



Fig. 2. Typical SEM images of the ceramics.

The competition between the two effects is presumed to be responsible for the shift of the XRD peak. Fig. 1(d) shows a magnified view of peaks around  $2\theta =$ 45°. The tetragonal symmetry is always characterized with the presence of (002) and (200) peaks around 45°. It is found that the splitting of the XRD peaks of BaTiO<sub>3</sub> is more obvious than that of BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-δ</sub>, suggesting a decrease in tetragonality for BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-8</sub>. The lattice parameters of the ceramics were refined by utilizing the program of MAUD with a model of P4mm [13]. After repeated refinement, the values of reliability index parameter  $(R_{wp})$  are less than 15% and the goodness of fit (Sig) has the value between  $1.1 \sim 1.3$ , which confirm the goodness of refinement. The Rietveld analysis results for BaTiO3 and BaTi\_{0.99}Fe\_{0.01}O\_{3-\delta} are demonstrated in Fig. 1(a) and Fig. 1(b), respectively. For BaTiO<sub>3</sub>, the lattice parameter a is 3.9996 Å and c is 4.0224 Å. The a and c decrease to 4.0021 Å and 4.0199 Å for  $BaTi_{0.99}Fe_{0.01}O_{3-\delta}$ , respectively. The tetragonality factor c/a-1 decreases from 0.57% for BaTiO<sub>3</sub> to 0.44% for BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-\delta</sub>.

The bulk densities of BaTiO<sub>3</sub> and BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-δ</sub> are 5.79 and 5.81 g/cm<sup>3</sup>, respectively; their relative densities are higher than 95%. SEM images of the ceramics are shown in Fig. 2. Both ceramics show dense microstructure. The mean grain sizes of BaTiO<sub>3</sub> and BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-δ</sub> are about 2.5 and 4.6  $\mu$ m, respectively. As is generally recognized, the presence of oxygen vacancies in oxide materials is beneficial to mass transport during sintering [15]. As mentioned above, oxygen vacancies were created in BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-δ</sub>



**Fig. 3.** Plots of dielectric constant vs. temperature for the ceramics. The inserts show the enlarged patterns around the Curie temperatures.

which may contribute to the promoted grain growth in  $BaTi_{0.99}Fe_{0.01}O_{3-\delta}$ .

Variations in dielectric constant  $(\varepsilon_r)$  of the ceramics as a function of temperature (T) are shown in Fig. 3. For a given frequency,  $\varepsilon_r$  increases gradually with an increase in T up to the maximum value of dielectric constant ( $\varepsilon_m$ ) and then decreases. The Curie temperature (T<sub>c</sub>) corresponding to ferroelectric-paraelectric phase transition can be determined at  $\varepsilon_m$ . A sharp peak appears at  $T_c$  on the  $\varepsilon_r \sim T$ curves of BaTiO<sub>3</sub>, while the peak of  $BaTi_{0.99}Fe_{0.01}O_{3-\delta}$ becomes broad. The inserts of Fig. 3 show the enlarged patterns around T<sub>c</sub>. It is found that the T<sub>c</sub> values do not change with the increase in frequency from 1 kHz to 1 MHz for a given specimen. For  $BaTiO_3$ , the  $T_c$  value is 125 °C and the  $\epsilon_m$  values at 1 kHz, 10 kHz, 100 kHz, 1 MHz are 8216, 8165, 8102, 8093, respectively. For BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3- $\delta$ </sub>, the T<sub>c</sub> value is 107 °C and the  $\varepsilon_m$ values at 1 kHz, 10 kHz, 100 kHz, 1 MHz are 4698, 4675, 4663, 4613, respectively. For both ceramics, the dielectric loss at room temperature is less than 2%. It is found that  $\varepsilon_m$  decreases with increasing frequency, which has been widely observed in BaTiO<sub>3</sub>-based ceramics [16]. The  $\varepsilon_m$  values of BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3- $\delta$ </sub> are lower than those of BaTiO<sub>3</sub>. It is believed that ferroelectric ceramics with higher oxygen vacancy concentration always have higher  $\varepsilon_m$  values, which is connected to electron relaxation polarization [9, 17]. The doping of Fe<sup>3+</sup> into BaTiO<sub>3</sub>



**Fig. 4.** Plots of the reciprocal of dielectric constant  $(1/\epsilon_r)$  at 1 kHz vs. temperature and the fitting plots by the Curie-Weiss law for BaTiO<sub>3</sub> (a) and BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3. $\delta}$ </sub> (b). The corresponding enlarged patterns around the Curie temperatures are shown in (c) and (d). The symbols denote experimental data, while the solid lines denote the least-squared fitting line to the Curie-Weiss law.

caused oxygen vacancies in the ceramic, which facilitates increasing  $\epsilon_m$  values. Additionally, the difference in  $\epsilon_m$  between BaTiO<sub>3</sub> and BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-δ</sub> is also related to the difference in lattice parameters. It is well known that intrinsic contribution to dielectric constant is from the relative anion/cation shift that preserves the ferroelectric crystal structure. A higher tetragonality always gives higher dielectric constant [18]. So, the decrease in tetragonality factor for BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-δ</sub> is partially responsible for the reduction of  $\epsilon_m$ .

The dielectric properties of the ceramics were studied via Curie-Weiss law;

$$1/\varepsilon_{\rm r} = (T - T_0)/C \tag{4}$$

where T<sub>0</sub> is Curie-Weiss temperature, and C is Curie constant. Fig. 4 shows the plots of  $1/\epsilon_r$  at 1 kHz vs. T and the fitting plots by the Curie-Weiss law for BaTiO<sub>3</sub> and BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-8</sub>. As shown in Fig. 4(a, c), the data shows a good linear dependence of  $1/\varepsilon_r$  vs. (T-T<sub>0</sub>) in the paraelectric state above T<sub>c</sub> for BaTiO<sub>3</sub>, suggesting the classical dielectric property of normal ferroelectric materials. It has been reported that the value of  $\Delta T = T_c - T_0$  is typically about  $8 \sim 15$  °C for BaTiO3 [19]. In this work,  $T_0$  is 112  $^o\!C$  and  $\Delta T$  is 13 °C. The Curie-Weiss plot for BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-δ</sub> is shown in Fig. 4(b, d). There exists a distinct deviation from Curie-Weiss law below about 113 °C in the paraelectric state. The  $T_0$  is 81 °C and lower than  $T_c$ with the value of 26 °C. G.A. Smolenskii pointed out that the order of phase transition can be determined by  $\Delta T$ , namely  $\Delta T = 0$  indicates the ferroelectricparaelectric phase transition is of a second-order type, while  $\Delta T > 0$  is of a first-order transition [20]. Here, the  $\Delta T$  values for both samples are larger than zero, suggesting a first-order type phase transition.

In order to further characterize the dielectric properties,



**Fig. 5.** Plots of  $Ln(1/\epsilon_r-1/\epsilon_m)$  vs.  $Ln(T-T_c)$  at 1 kHz for BaTiO<sub>3</sub> and BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-8</sub>. The symbols denote experimental data, while the solid lines denote the least-squared fitting line to the modified Curie-Weiss law.



Fig. 6. P-E loops of  $BaTiO_3$  and  $BaTi_{0.99}Fe_{0.01}O_{3.\delta}$  at 50 Hz and room temperature. The insert shows the enlarged pattern under the electric fields of  $-20 \sim 20 \text{ kV/cm}$ .

a modified Curie-Weiss law was also used [21]:

$$1/\varepsilon_{\rm r} - 1/\varepsilon_{\rm m} = (\mathrm{T} - \mathrm{T}_{\rm c})^{\gamma}/\mathrm{C}' \tag{5}$$

where  $\varepsilon_m$  is the maximum value of dielectric constant at the Curie temperature  $T_c$ , C' is the Curie-like constant, and g is the degree of diffuseness. g is usually ranging from 1 for a normal ferroelectric to 2 for an ideal relaxor ferroelectric. Plots of  $Ln(1/\varepsilon_r-1/\varepsilon_m)$  as a function of  $Ln(T-T_c)$  at 1 kHz for BaTiO<sub>3</sub> and BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-δ</sub> are shown in Fig. 5. Both samples demonstrate a linear relationship. By least-squared fitting the experimental data to the modified Curie-Weiss law, g was determined. The calculated g for BaTiO<sub>3</sub> is 1.1, while that for BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-δ</sub> increases to 1.4. The increase in g implies diffuse character in BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-δ</sub>. The diffuse phase transition behavior is considered to be close related to the coexistence of complex cations (Fe<sup>3+</sup> and Ti<sup>4+</sup>) at an equivalent crystallographic site [22, 23]. Furthermore, the formation of oxygen vacancies in BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3- $\delta$ </sub> can increase the local compositional heterogeneity and therefore contributes to more diffusive characteristic of phase transition.

Fig. 6 shows polarization of BaTiO3 and BaTi0.99Fe0.01O3-8 versus electric field (Eappl) measured at 50 Hz and room temperature. Clear hysteresis loop is observed for BaTiO<sub>3</sub>, which is typical shape for ferroelectric materials. The hysteresis curve of BaTi0.99Fe0.01O3-8 becomes slim. The hysteresis loops are not completely closed at negative y axis, which is due to the pre-loop delay in the measurement [24]. The remnant polarization  $(P_r)$ , maximum polarization (P<sub>m</sub>) and coercive field (E<sub>c</sub>) of the samples were estimated from the hysteresis loops. BaTiO<sub>3</sub> shows  $P_r$  of 2.25  $\mu$ C cm<sup>2</sup>,  $P_m$  of 15.76  $\mu$ C/cm<sup>2</sup> and  $E_c$  of 3.07 kV/cm under  $E_{appl}$ = 55 kV/cm. For BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3- $\delta$ </sub>, the values of P<sub>r</sub>, P<sub>m</sub> and  $E_c$  are 0.21  $\mu$ C/cm<sup>2</sup>, 9.49  $\mu$ C/cm<sup>2</sup> and 1.45 kV/cm, respectively. The slimmed hysteresis curve causes lower  $P_r$ ,  $P_m$  and  $E_c$  values for  $BaTi_{0.99}Fe_{0.01}O_{3-\delta}$ . The polarization of ferroelectric materials is associated with the distance between the centers of cations and anions in the crystal structure. The coercive field represents the difficulty of domain alignment which is related to the distorted degree of crystal structure and point defects [25, 26]. For the ceramics with tetragonal phase, the distance between the centers of cations and anions in the crystal structure is mainly determined by the lattice constants (a, c). The distorted degree of crystal structure is characterized by the tetragonality factor (c/a-1). The lattice parameter c of BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3-δ</sub> decreases compared with that of BaTiO<sub>3</sub>. So, a less distorted crystal structure due to the doping of Fe<sup>3+</sup> into BaTiO<sub>3</sub> contributes to a decrease of ferroelectric properties. In addition, Fe<sup>3+</sup> substituted  $Ti^{4+}$  in  $BaTi_{0.99}Fe_{0.01}O_{3-\delta}$ , which caused an increase in oxygen vacancy concentration. Oxygen vacancies are unfavorable to domain switching, which also led to a decrease in ferroelectric properties [27, 28].

# Conclusions

BaTiO<sub>3</sub> and BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3- $\delta}$ </sub> were prepared via the solid state reaction method. Both ceramics show pure perovskite structure with the tetragonal phase. The lattice parameters a and c of BaTiO<sub>3</sub> are 3.9996 Å and 4.0224 Å, respectively. For BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3- $\delta$ </sub>, the a and c decrease to 4.0021 Å and 4.0199 Å, respectively. The doping of Fe<sup>3+</sup> into BaTiO<sub>3</sub> caused a decrease in grain size. Compared with BaTiO<sub>3</sub>, BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3- $\delta$ </sub> shows decreased dielectric constant, decreased Curie temperature, and increased diffuse character. The ferroelectric property of BaTi<sub>0.99</sub>Fe<sub>0.01</sub>O<sub>3- $\delta$ </sub> decreased compared with that of BaTiO<sub>3</sub>. The change in ferroelectric property was also discussed.

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# References

- G. Arlt, D. Hennings, G. de With, J. Appl. Phys. 58 (1985) 1619-1625.
- 2. G.H. Haertling, J. Am. Ceram. Soc. 82 (1999) 797-818.
- H. Gong, X. Wang, S. Zhang, H. Wen, L. Li, J. Eur. Ceram. Soc. 34 (2014) 1733-1739.
- L. Zhang, H. Pan, H. Liu, B. Zhang, L. Jin, M. Zhu, W. Yang, J. Alloys Compds. 643 (2015) 247-252.
- M.T. Buscaglia, V. Buscaglia, M. Viviani, P. Nanni, M. Hanuskova, J. Eur. Ceram. Soc. 20 (2000) 1997-2007.
- Y. Ichikawa, Y. Kitanaka, T. Oguchi, Y. Noguchi, M. Miyayama, J. Ceram. Soc. Jap. 122 (2014) 373-380.
- X. Wang, H.L.-W. Chan, C. Choy, J. Eur. Ceram. Soc. 24 (2004) 1227-1231.
- Y. Wang, B. Cui, Y. Liu, X. Zhao, Z. Hu, Q. Yan, T. Wu, L. Zhao, Y. Wang, Script Mater. 90-91 (2014) 49-52.
- S.W. Zhang, H.L. Zhang, B.P. Zhang, G.L. Zhao, J. Eur. Ceram. Soc. 29 (2009) 3235-3242.
- J.G. Fisher, D. Rout, K.S. Moon, S.J.L. Kang, Mater. Chem. Phys. 120 (2010) 263-271.
- 11. Y.I. Jung, S.Y. Choi, S.J.L. Kang, Acta Mater. 54 (2006) 2849-2855.
- I. Fujii, M. Ugorek, Y. Han, S. Trolier-McKinstry, J. Am. Ceram. Soc. 93 (2010) 1081-1088.
- 13. The MAUD program: http://maud.radiographema.com.
- 14. R.D. Shannon, Acta Crystallogr. A 32 (1976) 751-767.
- X.M. Chen, W.Y. Pan, H.H. Tian, X.X. Gong, X.B. Bian, P. Liu, J. Alloys Compds. 509 (2011) 1824-1829.
- M.E. Lines, A.M. Glass, Principles and applications of ferroelectrics and related materials, Oxford University Press (2001).
- A. Tkach, P.M. Vilarinho, A.L. Kholkin, Acta Mater. 54 (2006) 5385-5391.
- 18. J. Rani, K.L. Yadav, S. Prakash, Mater. Sci. Eng. B 178 (2013) 1469-1475.
- L. Benguigui, Y. Beaucamps, Phys. Rev. B 23 (1981) 5866-5870.
- 20. G.A. Smolenskii, J. Phys. Soc. Jpn. 28 (1970) 26-37.
- 21. K. Uchino, S. Nomura, L.E. Cross, S.J. Jang, R.E. Newnham, J. Appl. Phys. 51 (1980) 1142-1145.
- 22. Q. Xu, D.P. Huang, M. Chen, W. Chen, H.X. Liu, B.-H. Kim, J. Alloy Compd. 471 (2009) 310-316.
- 23. X.M. Chen, X.X. Gong, T.N. Li, Y. He, P. Liu, J. Alloys Compds. 507 (2010) 535-541.
- 24. Radiant loop tracer manual: radiant technologies Inc., Application Note, April, 2004.
- 25. W.C. Lee, Y.F. Lee, M.H. Tseng, C.Y. Huang, Y.C. Wu, J. Am. Ceram. Soc. 92 (2009) 1069-1073.
- 26. X.M. Chen, H.Y. Ma, W.Y. Pan, M. Pang, P. Liu, J.P. Zhou, Mater. Chem. Phys. 132 (2012) 368-374.
- T. Friessnegg, S. Aggarwal, R. Ramesh, B. Nielsen, E.H. Poindexter, D.J. Keeble, Appl. Phys. Lett. 77 (2000) 127-129.
- X.M. Chen, J. Wang, H.Y. Ma, H.L. Lian, P. Liu, J. Ceram. Process Res. 13 (2012) 495-499.